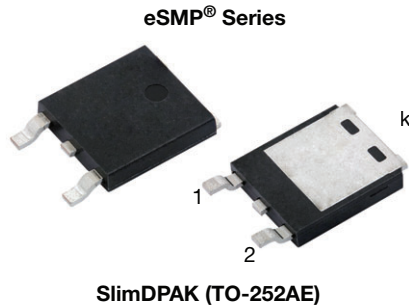
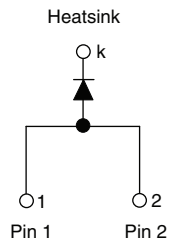


## Hyperfast Rectifier, 8 A FRED Pt®



SlimDPAK (TO-252AE)



### FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$  and soft recovery
- For PFC CRM / CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


 RoHS  
COMPLIANT  
HALOGEN  
**FREE**

### LINKS TO ADDITIONAL RESOURCES


[3D Models](#)

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	8 A
$V_R$	600 V
$V_F$ at $I_F$	1.3 V
$t_{rr}$ (typ.)	16 ns
$T_J$ max.	175 °C
Package	SlimDPAK (TO-252AE)
Circuit configuration	Single

### TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### MECHANICAL DATA

**Case:** SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base PN/-M3 - halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 144$ °C	8	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25$ °C, 10 ms sine pulse wave	90	
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25$ °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100$ $\mu$ A	600	-	-	V
Forward voltage	$V_F$	$I_F = 8$ A	-	1.6	2.40	
		$I_F = 8$ A, $T_J = 150$ °C	-	1.3	1.7	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	20	$\mu$ A
		$T_J = 150$ °C, $V_R = V_R$ rated	-	-	500	
Junction capacitance	$C_T$	$V_R = 600$ V	-	12	-	pF



DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	$t_{rr}$	$I_F = 1\text{ A}$ , $di_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	21	-	ns	
		$I_F = 1\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	16	-		
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{RR} = 0.25\text{ A}$	-	-	25		
		$T_J = 25\text{ }^\circ\text{C}$	-	25	-		
		$T_J = 125\text{ }^\circ\text{C}$	-	65	-		
Peak recovery current	$I_{RRM}$	$I_F = 8\text{ A}$ $di_F/dt = 500\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	$T_J = 25\text{ }^\circ\text{C}$	-	4.9	-	A
			$T_J = 125\text{ }^\circ\text{C}$	-	8.2	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	$T_J = 25\text{ }^\circ\text{C}$	-	90	-	nC
			$T_J = 125\text{ }^\circ\text{C}$	-	260	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^\circ\text{C}$
Thermal resistance, junction to mount	$R_{thJM}$		-	-	2.2	$^\circ\text{C}/\text{W}$
Marking device		Case style SlimDPAK (TO-252AE)	8EVH06			

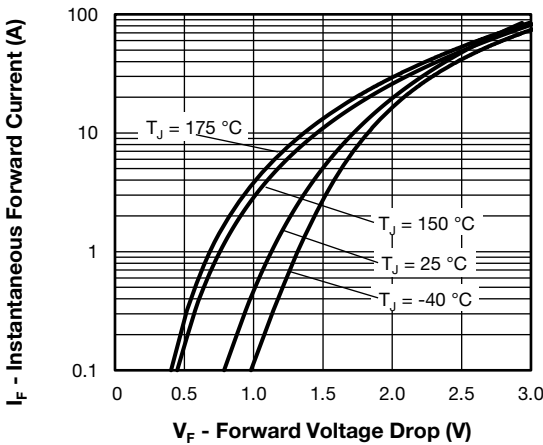


Fig. 1 - Typical Forward Voltage Drop Characteristics

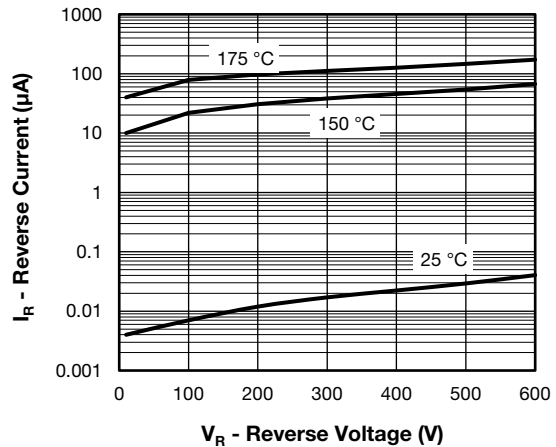


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

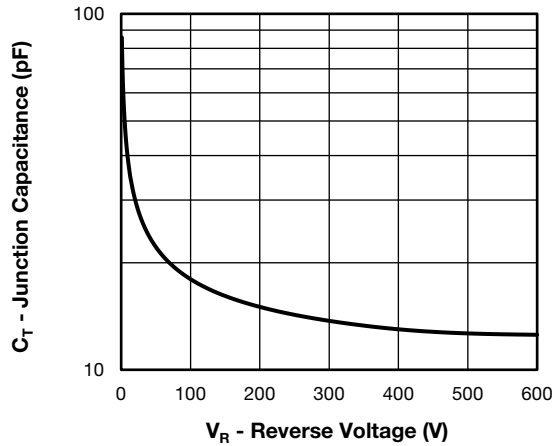


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

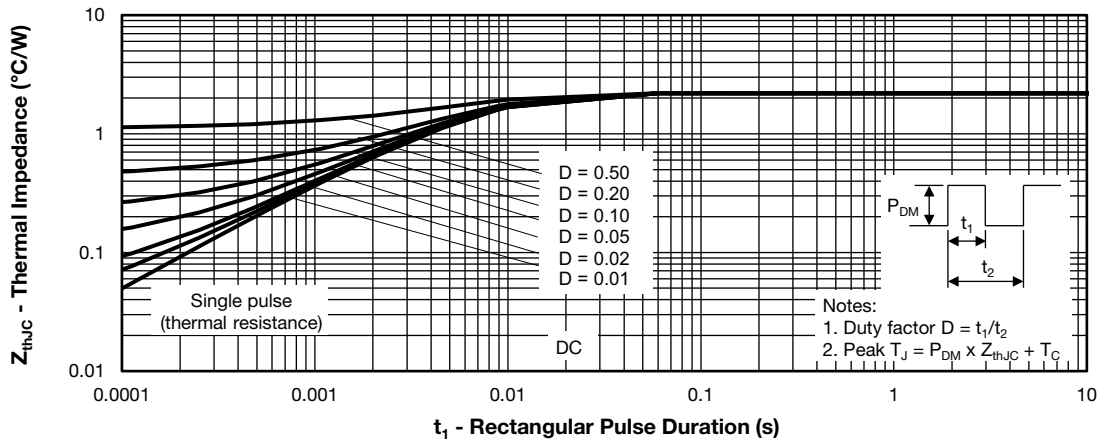


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

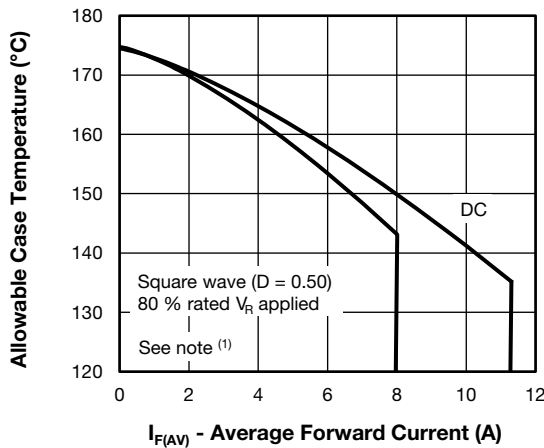


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

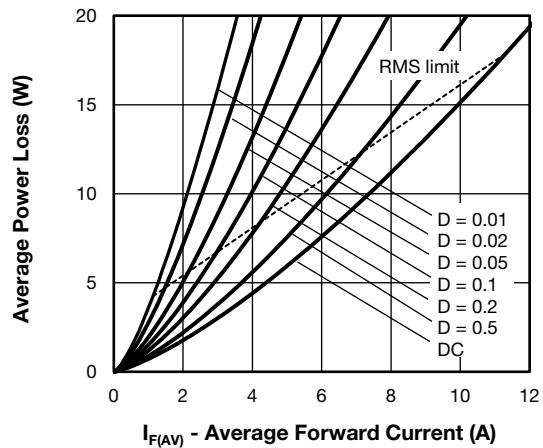


Fig. 6 - Forward Power Loss Characteristics

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

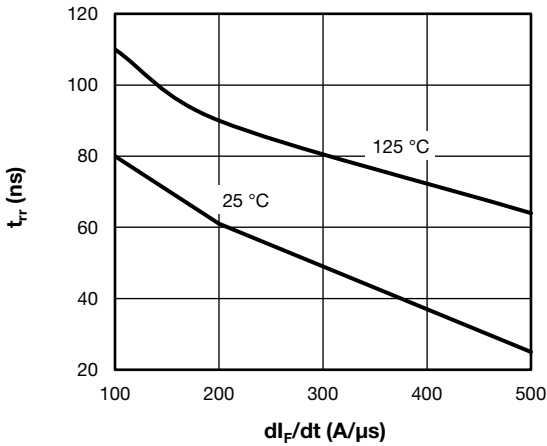


Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$

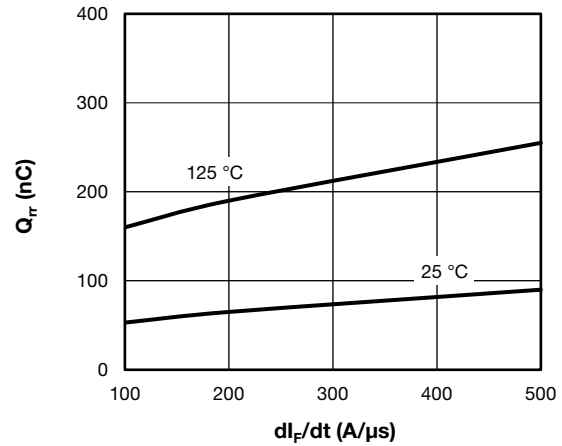
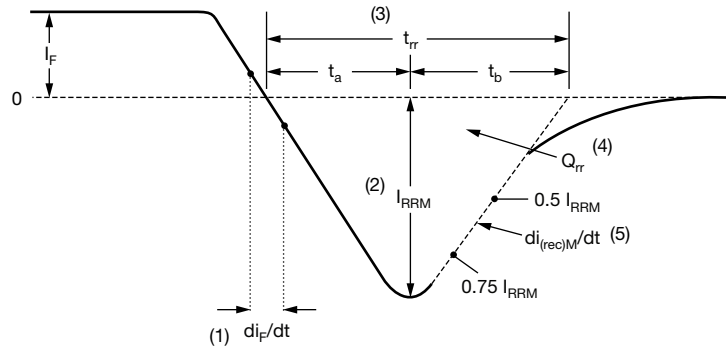


Fig. 8 - Typical Stored Charge vs.  $di_F/dt$



- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

- (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

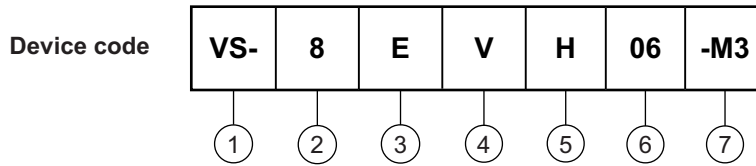
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions



### ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (8 = 8 A)
- 3** - Circuit configuration:  
E = single die
- 4** - V = SlimDPAK
- 5** - Process type:  
H = hyperfast recovery
- 6** - Voltage code (06 = 600 V)
- 7** - Environmental digit:  
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

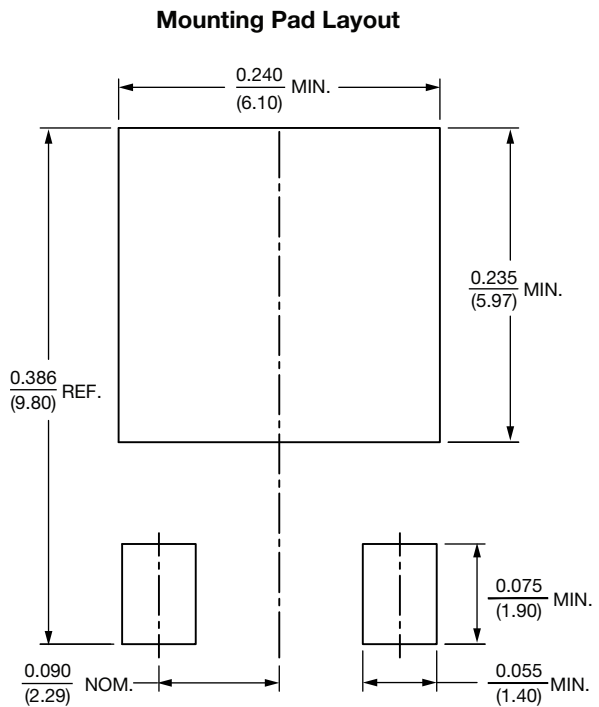
ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION
VS-8EVH06-M3/I	0.20	I	4500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?96081">www.vishay.com/doc?96081</a>
Part marking information	<a href="http://www.vishay.com/doc?96085">www.vishay.com/doc?96085</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>



### SlimDPAK

**DIMENSIONS** in inches (millimeters)





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